



DMT31M1LPSW

### 30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> Tc = +25°C
30V	0.95mΩ @ V <sub>GS</sub> = 10V	130A
300	1.5mΩ @ V <sub>GS</sub> = 4.5V	111A

## **Description and Applications**

This new generation MOSFET is designed to minimize  $R_{DS(ON)}$  yet maintain superior switching performance. This device is ideal for use in notebook battery power managements and load switches.

- Body control electronics
- DC-DC converters

#### Features

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Thermally Efficient Package-Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On-State Losses < 1.1mm Package Profile – Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)

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Top View

Pin Configuration

ПD

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Weight: 0.097 grams (Approximate)

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Internal Schematic



# Ordering Information (Note 4)

Orderable Part Number	Baakaga	Packing			
	Package	Qty.	Carrier		
DMT31M1LPSW-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel		

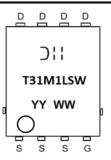
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Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



] | | = Manufacturer's Marking T31M1LS<u>W</u> = Product Type Marking Code YYWW or YYWW = Date Code Marking YY or  $\overline{YY}$  = Last Two Digits of Year (ex: 24 = 2024) WW = Week Code (01 to 53)



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	30	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 7)	Tc = +25°C Tc = +70°C	ID	130 111	А
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lD	40 32	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	500	А
Maximum Continuous Body Diode Forward Current (Note 6)	ls	4.2	A	
Pulsed Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)		Isм	500	А
Avalanche Current, L = 0.1mH (Note 8)		las	76	А
Avalanche Energy, L = 0.1mH (Note 8)		Eas	296	mJ

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		Po	1.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	70	°C/W
Total Power Dissipation (Note 6)		PD	3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	42	°C/W
Thermal Resistance, Junction to Case (Note 7)		R <sub>θJC</sub>	3.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 9)								
Drain-Source Breakdown Voltage	BVDSS	30	_	—	V	$V_{GS} = 0$ , $I_D = 1mA$		
Zero Gate Voltage Drain Current	IDSS			1	μA	$V_{DS} = 24V, V_{GS} = 0$		
Gate-Source Leakage	lgss	—		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0$		
ON CHARACTERISTICS (Note 9)	ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(th)	1.3		2.3	V	$V_{DS} = V_{GS}, I_D = 1mA$		
Static Drain-Source On-Resistance	Descent	—	0.7	0.95	mΩ	VGS = 10V, ID = 30A		
Static Drain-Source On-Resistance	RDS(ON)	_	0.9	1.5	11122	$V_{GS} = 4.5V, I_D = 30A$		
Diode Forward Voltage	Vsd	—	0.7	1.2	V	V <sub>GS</sub> = 0, I <sub>S</sub> = 30A		
DYNAMIC CHARACTERISTICS (Note 10)								
Input Capacitance	Ciss	_	5938	—	pF	1/ AFX/ 1/ 0		
Output Capacitance	Coss	—	4806	—	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0, f = 1MHz		
Reverse Transfer Capacitance	Crss	_	201	—	pF			
Gate Resistance	Rg	—	0.2	_	Ω	V <sub>DS</sub> = 0, V <sub>GS</sub> = 0, f = 1MHz		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	86	—	nC			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	39	_	nC			
Gate-Source Charge	Qgs	_	13	_	nC	− V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A −		
Gate-Drain Charge	Qgd	_	7	_	nC			
Turn-On Delay Time	tD(ON)	_	12	_	ns			
Turn-On Rise Time	t <sub>R</sub>		28	_	ns	V <sub>DD</sub> = 15V, V <sub>GEN</sub> = 10V,		
Turn-Off Delay Time	tD(OFF)	—	82	—	ns	R <sub>GEN</sub> = 4.7Ω, I <sub>D</sub> = 30A		
Turn-Off Fall Time	tF	_	45	—	ns	1		

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .

9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.





125°C

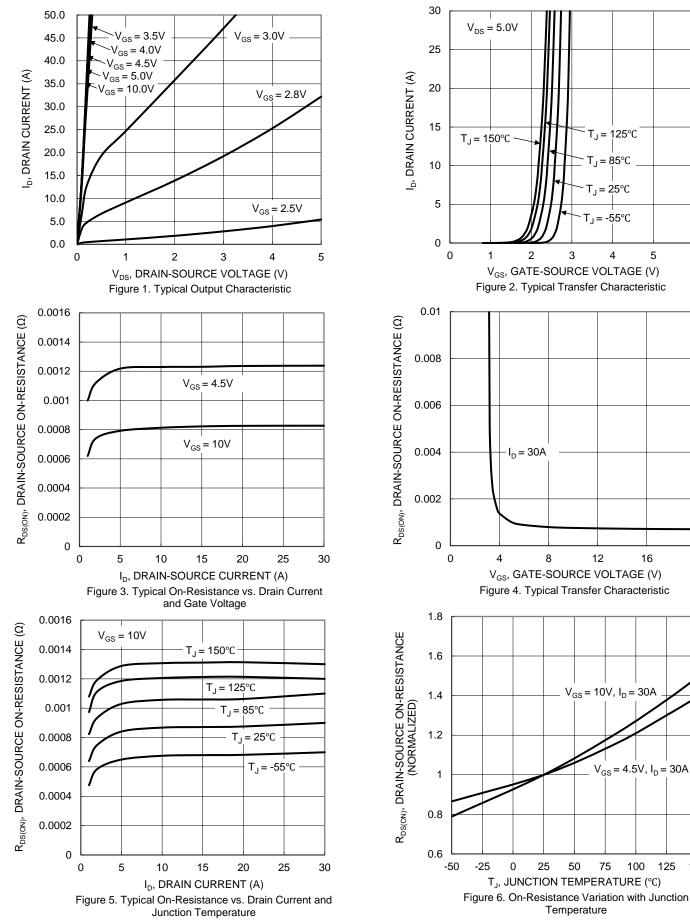
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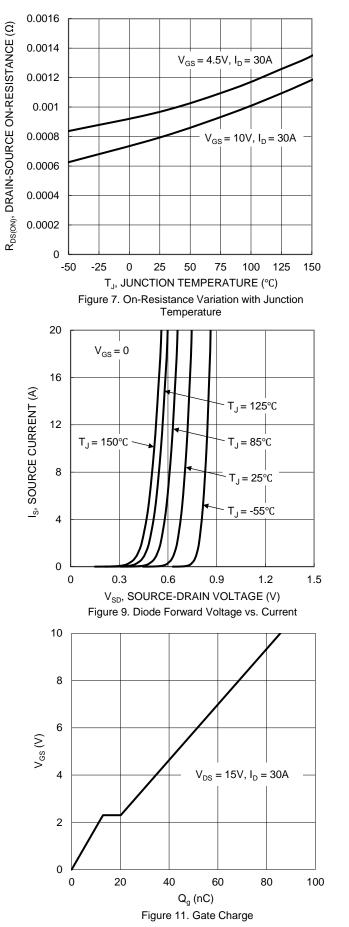
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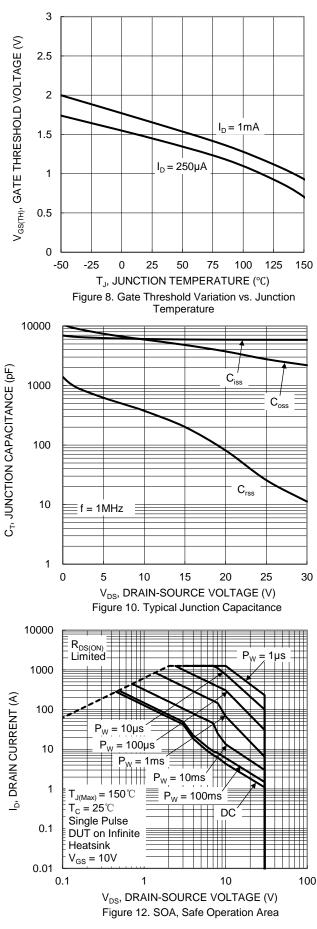
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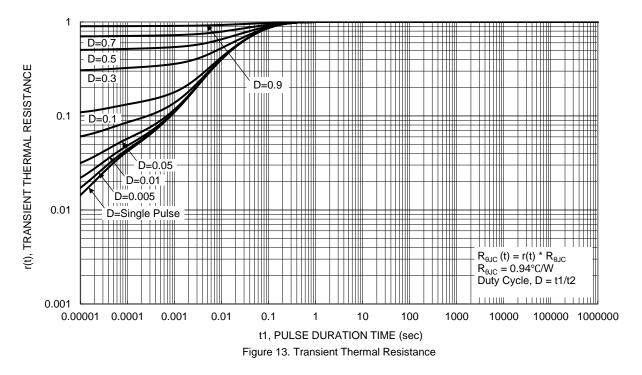
# DMT31M1LPSW





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PowerDI5060-8/SWP

(Type UX)

Max

1.10

0.05

0.50

0.35

0.330

5.10

3.96

4.18

6.00

3.86

1.27BSC

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0.835

12°

8°

All Dimensions in mm

4.595 4.395

0.835 0.735

0.400 0.300

0.225 0.125

4.005 3.605

6.40 BSC

0.25REF

5.15 BSC

Тур

1.00

---

0.41 0.25

0.277

4.90

3.76

3.98

5.80

3.66

---

0.735

11°

7°

Min

0.90

0

0.30

0.20

0.230

4.70

3.56

3.78

5.60

3.46

4.195

1.05

0.635

0.635

0.200

0.025

3.205

10°

6°

Α A1

b

b2 b4

С

D

D1

D2

Ε

E1

E2

е

k

L

La

L1

L4

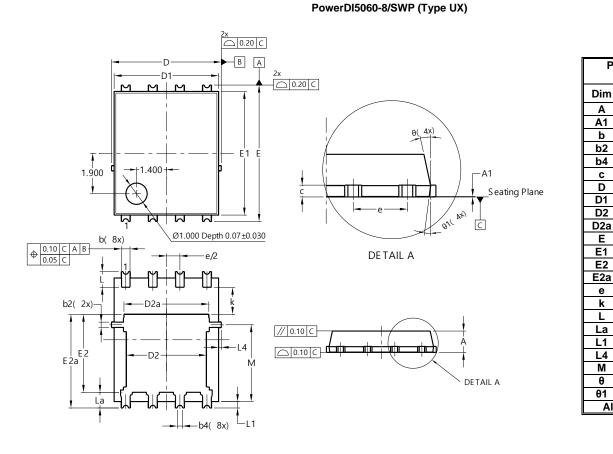
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# **Package Outline Dimensions**

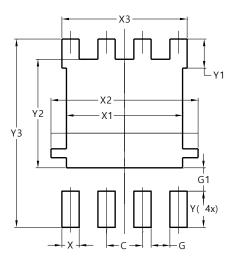
Please see http://www.diodes.com/package-outlines.html for the latest version.



## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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